

2SD844

SILICON NPN TRIPLE DIFFUSED TYPE

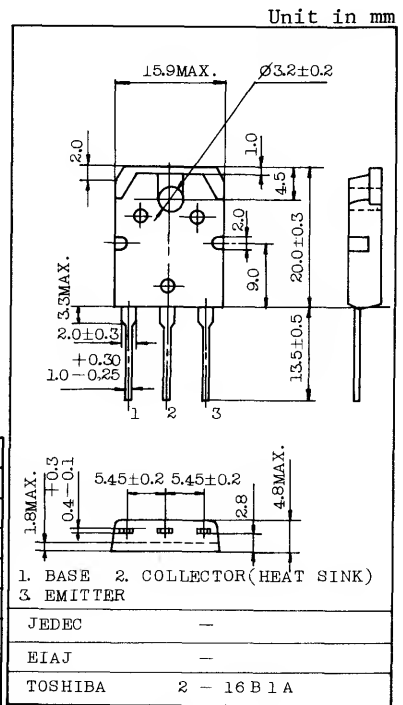
HIGH CURRENT SWITCHING APPLICATIONS.
POWER AMPLIFIER APPLICATION.

FEATURES:

- High Collector Current : $I_C=7A$
- Low Collector Saturation Voltage
: $V_{CE(sat)}=0.4V(\text{Max.})$ (at $I_C=4A$)
- High Power dissipation : $P_C=60W$ (at $T_c=25^\circ C$)
- Complementary to 2SB754.

MAXIMUM RATINGS (Ta=25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|-----------------------------|------------------|---------|------|
| Collector-Base Voltage | V _{CB0} | 50 | V |
| Collector-Emitter Voltage | V _{CE0} | 50 | V |
| Emitter-Base Voltage | V _{EBO} | 5 | V |
| Collector Current | I _C | 7 | A |
| Emitter Current | I _E | -7 | A |
| Collector Power Dissipation | P _C | Ta=25°C | 2.5 |
| | | Tc=25°C | 60 |
| Junction Temperature | T _j | 150 | °C |
| Storage Temperature Range | T _{stg} | -55~150 | °C |



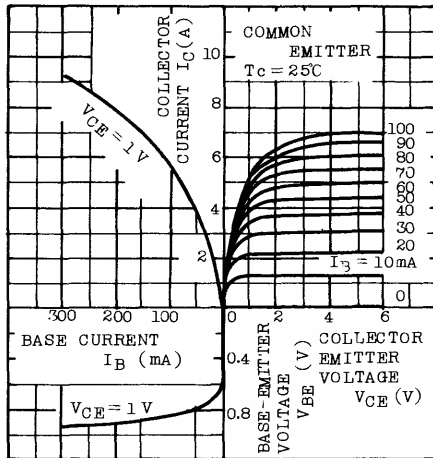
Weight : 4.6g

ELECTRICAL CHARACTERISTICS (Ta=25°C)

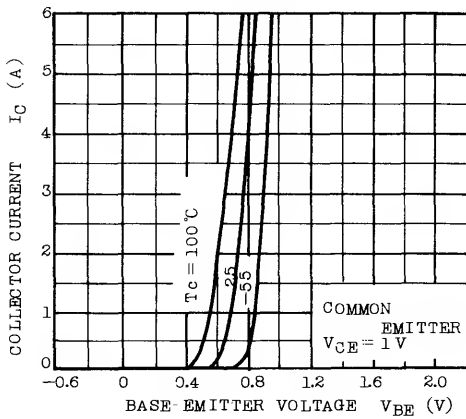
| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX | UNIT |
|--------------------------------------|-------------------------------|---|------|------|-----|------|
| Collector Cut-off Current | I _{CB0} | V _{CB} =50V, I _E =0 | - | - | 10 | µA |
| Emitter Cut-off Current | I _{EBO} | V _{EB} =5V, I _C =0 | - | - | 10 | µA |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | I _C =50mA, I _B =0 | 50 | - | - | V |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | I _E =10mA, I _C =0 | 5 | - | - | V |
| DC Current Gain | h _{FE} (1) (Note) | V _{CE} =1V, I _C =1A | 70 | - | 240 | |
| | h _{FE} (2) | V _{CE} =1V, I _C =4A | 30 | - | - | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | I _C =4A, I _B =0.4A | - | 0.2 | 0.4 | V |
| Base-Emitter Voltage | V _{BE} | V _{CE} =1V, I _C =4A | - | 0.9 | 1.2 | V |
| Transition Frequency | f _T | V _{CE} =5V, I _C =1A | - | 15 | - | MHz |
| Collector Output Capacitance | C _{ob} | V _{CB} =10V, I _E =0, f=1MHz | - | 250 | - | pF |

Note : h_{FE}(1) Classification O : 70 ~ 140, Y : 120 ~ 240

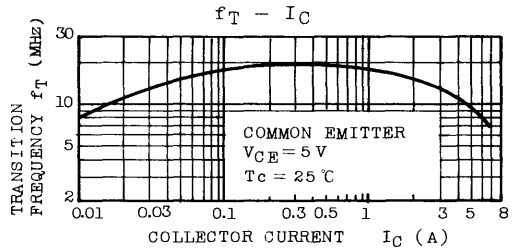
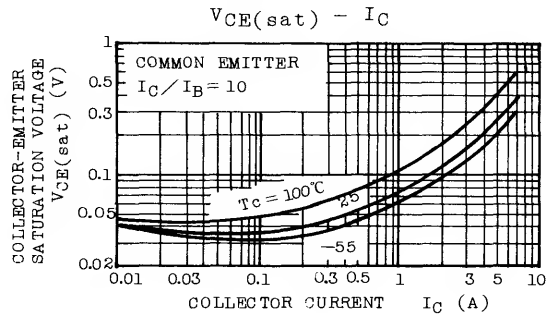
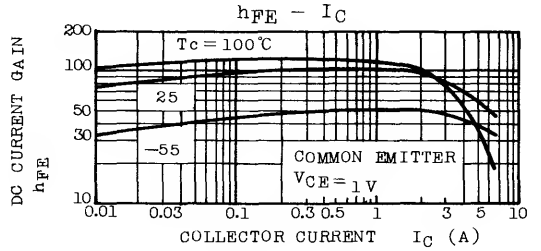
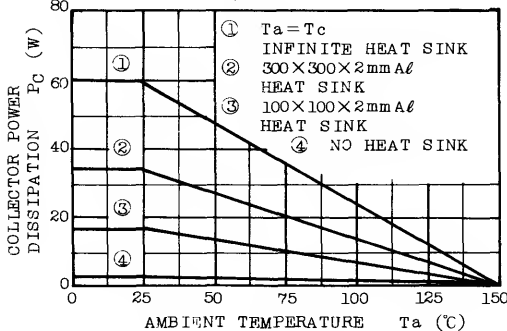
STATIC CHARACTERISTICS



$I_C - V_{BE}$



$P_C - T_a$



SAFE OPERATING AREA

